

March 1994 Revised November 1999

74ABT2240

Octal Buffer/Line Driver with 25 Ω Series Resistors in the Outputs

General Description

The ABT2240 is an inverting octal buffer and line driver designed to drive the capacitive inputs of MOS memory drivers, address drivers, clock drivers, and bus-oriented transmitters/receivers.

The 25Ω series resistors in the outputs reduce ringing and eliminate the need for external resistors.

Features

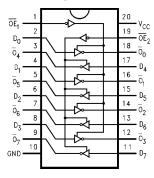
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description			
74ABT2240CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body			
74ABT2240CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
74ABT2240CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide			
74ABT2240CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			

Devices also available in Tape and Reel. Specify by appending letter suffix "X" to the ordering code.

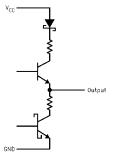
Connection Diagram



Pin Descriptions

Pin Names	Descriptions				
$\overline{OE}_1, \overline{OE}_2$	Output Enable Input (Active LOW)				
D ₀ –D ₇	Data Inputs				
$\overline{O}_0 - \overline{O}_7$	Outputs				

Schematic of Each Output



Truth Table

OE ₁	I ₀₋₃	Ō ₀₋₃	OE ₂	I ₄₋₇	Ō _{4–7}
Н	Х	Z	Н	Х	Z
L	Н	L	L	Н	L
L	L	Ι	L	L	н

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

Z = High Impedance

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Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions

Storage Temperature -65°C to $+150^{\circ}\text{C}$ Ambient Temperature under Bias -55°C to $+125^{\circ}\text{C}$

Ambient Temperature under Bias -55°C to $+125^{\circ}\text{C}$ Junction Temperature under Bias -55°C to $+150^{\circ}\text{C}$ V_{CC} Pin Potential to Ground Pin -0.5V to +7.0V

Voltage Applied to Any Output

in the Disabled or

Power-off State -0.5 V to 5.5 V in the HIGH State $-0.5 \text{V to } \text{V}_{\text{CC}}$

Current Applied to Output

in LOW State (Max) $\qquad \qquad \text{twice the rated I}_{\text{OL}} \, (\text{mA})$

DC Latchup Source Current

(Across Comm Operating Range) -300 mA Over Voltage Latchup (I/O) 10V Free Air Ambient Temperature $-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$ Supply Voltage +4.5V to +5.5V

Minimum Input Edge Rate ($\Delta V/\Delta t$)

Data Input 50 mV/ns
Enable Input 20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation

under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

ViH Input HIGH Voltage 2.0 V Recognized HIGH Signal VIL Input LOW Voltage 0.8 V Recognized LOW Signal VCD Input Clamp Diode Voltage -1.2 V Min I _{IN} = -18 mA VOH Output HIGH 2.5 V Min IOH = -3 mA Voltage 2.0 V Min IOH = -32 mA VOL Output LOW Voltage 0.8 V Min IOH = -32 mA IH Input HIGH Current 1 μA Max VIN = 2.7V (Note 3) VIN = 7.0V VIN = 0.5V (Note 3) VIN = 0.0V (Note 3) VIN = 0.5V (Note 3) VIN = 0.0V (Note 3) VIN =	
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Voltage Z.0	
Vol	
Input HIGH Current 1	
I _{BVI} Input HIGH Current Breakdown Test 7	
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ViD Input Leakage Test V 0.0 Inp = 1.9 μA All Other Pins Grounded IozH Output Leakage Current 10 μA 0 - 5.5V VouT = 2.7V; OEn = 2.0V IozL Output Leakage Current -10 μA 0 - 5.5V VouT = 0.5V; OEn = 2.0V Ios Output Short-Circuit Current -275 mA Max VouT = 0.0V IcEX Output HIGH Leakage Current 50 μA Max VouT = V CC Izz Bus Drainage Test 100 μA 0.0 VouT = 5.5V; All Others (Country Incomplete Country I	
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I _{CCH} Power Supply Current 50 μA Max All Outputs HIGH I _{CCL} Power Supply Current 30 mA Max All Outputs LOW	
I _{CCL} Power Supply Current 30 mA Max All Outputs LOW	ND
992 117	
I_{CCZ} Power Supply Current 50 μA Max $\overline{OE}n = V_{CC}$	
All Others at V _{CC} or GND	
I_{CCT} Additional Outputs Enabled 1.5 mA $V_1 = V_{CC} - 2.1V$	
I_{CC} /Input Outputs 3-STATE 1.5 mA Max Enable Input $V_1 = V_{CC} - 2$.1V
Outputs 3-STATE 50 μA Data Input $V_{I} = V_{CC} - 2.1$	/
All Others at V _{CC} or GND	
I _{CCD} Dynamic I _{CC} No Load mA/ Outputs OPEN	
(Note 3) 0.1 MHz Max OEn = GND (Note 4)	
One Bit Toggling, 50% D	

Note 3: Guaranteed, but not tested.

Note 4: For 8 bits toggling, $I_{CCD} < 0.8 \text{ mA/MHz}$.

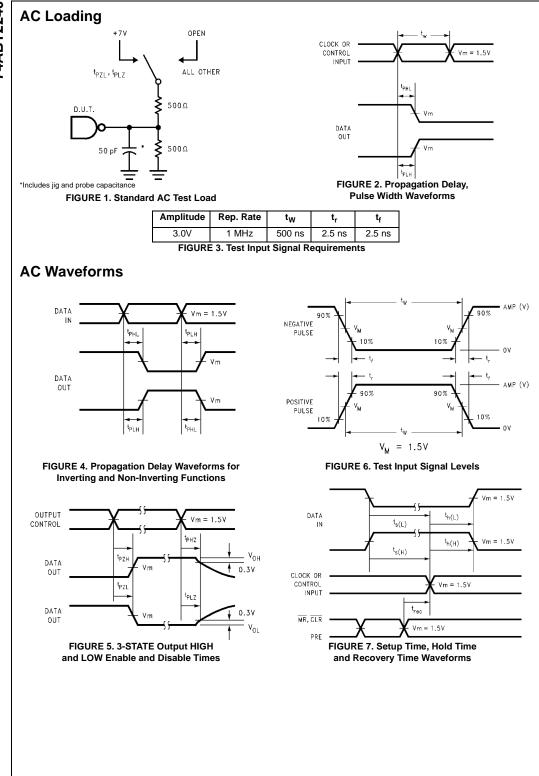
AC Electrical Characteristics

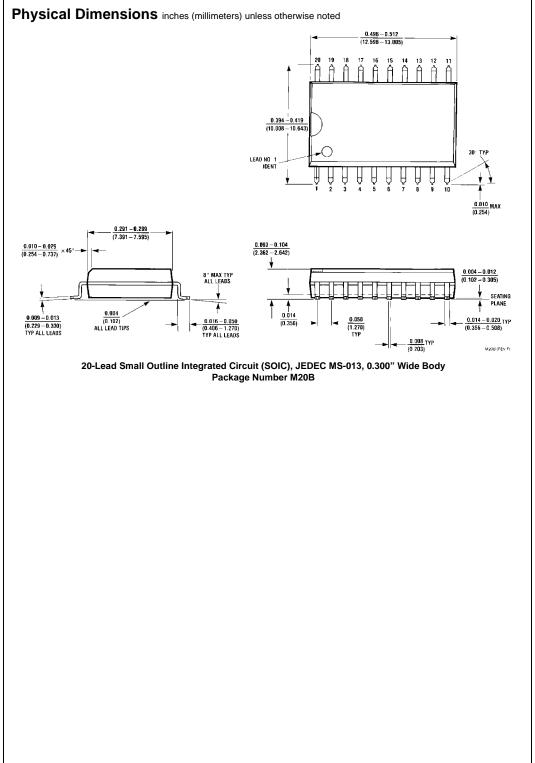
Symbol	Parameter		$T_A = +25$ °C $V_{CC} = +5V$ $C_L = 50 \text{ pF}$		$T_A = -40^{\circ}C$ $V_{CC} = 4$ $C_L =$	5V-5.5V	Units
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation	1.0		4.9	1.0	4.9	ns
t _{PHL}	Delay Data to Outputs	1.5		5.3	1.5	5.3	115
t _{PZH}	Output Enable	1.5		6.6	1.5	6.6	ns
t _{PZL}	Time	2.7		6.9	2.7	6.9	115
t _{PHZ}	Output Disable	1.9		6.4	1.9	6.4	ne
t _{PLZ}	Time	1.9		6.4	1.9	6.4	ns

Capacitance

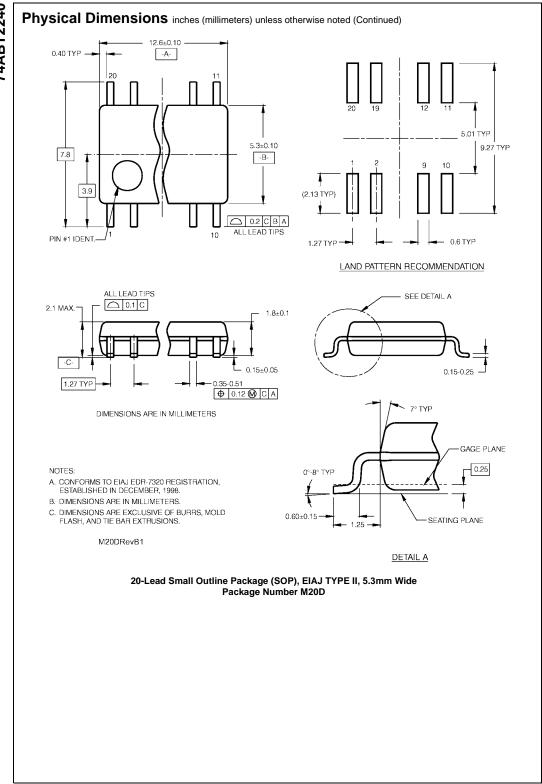
Symbol	Parameter	Тур	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	5.0	pF	V _{CC} = 0V
C _{OUT} (Note 5)	Output Capacitance	9.0	pF	V _{CC} = 5.0V

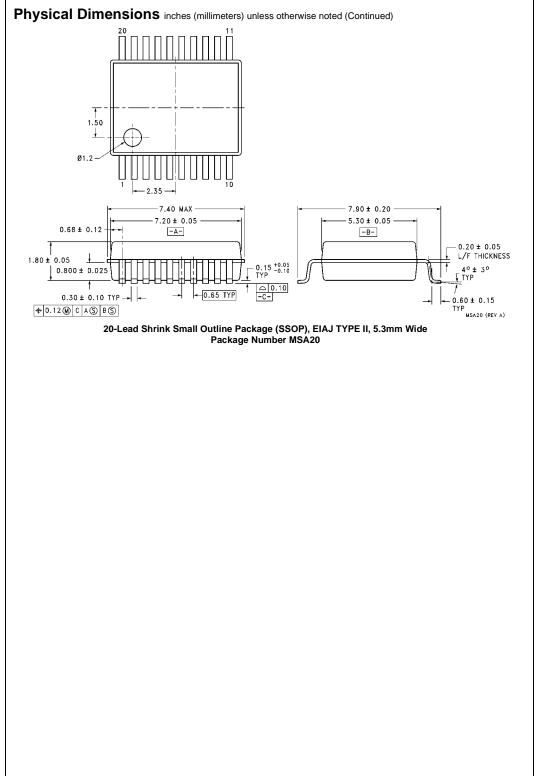
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.



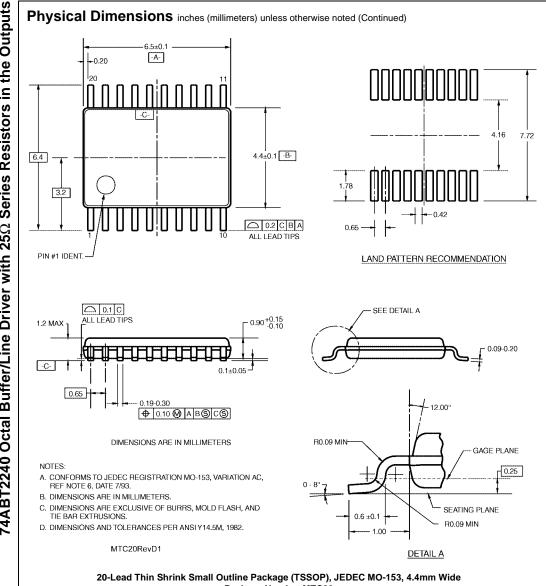


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Package Number MTC20

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